

## 639 nm Laser Diode, 10 mW

**HL6358MG** 



## **Description**

This 639 nm, 10 mW TO packaged laser diode is a compact light source that outputs a single transverse mode and is suited for a variety of applications such as a laser level, laser scanner, or a light source for optical equipment. It is packaged in a standard Ø5.6 mm TO can package and has an A pin configuration. This laser diode is compatible with our line of laser diode and TEC controllers as well as our selection of collimation solutions and TO can laser diode mounts.

## **Specifications**

Absolute Maximum Ratings <sup>a</sup>				
Specification	Maximum			
Optical Output Power, CW	12 mW			
LD Reverse Voltage	2 V			
PD Reverse Voltage	30 V			
Operating Temperature	-10 °C to 50 °C			
Storage Temperature	-40 °C to 85 °C			



a. Absolute Maximum Rating specifications should never be exceeded. Operating at or beyond these conditions can permanently damage the laser.

HL6358MG Specifications <sup>a</sup>							
		Symbol	Min	Typical	Max		
Center Wavelength @ Pop		λο	630 nm	639 nm	643 nm		
Optical Output Power, CW		P <sub>op</sub>	-	10 mW	-		
Threshold Current		I <sub>TH</sub>	-	25 mA	35 mA		
Operating Current, CW @ P <sub>op</sub>		I <sub>op</sub>	-	40 mA	50 mA		
Operating Voltage @ Pop		$V_{op}$	-	2.4 V	3.0 V		
Slope Efficiency		η	-	0.8 mW/mA	-		
Beam Divergence (FWHM) @ P <sub>op</sub>	Parallel	θ//	6°	8°	11°		
	Perpendicular	$ heta_{\perp}$	16°	21°	24°		
Monitor Current @ Pop		$I_{PD}$	0.5 mA	1.2 mA	2.0 mA		

a.  $T_{CASE} = 25$  °C if not specified.



## **Drawing**





